

# HSU88

## Silicon Schottky Barrier Diode for Detector and Mixer

REJ03G0140-0800Z (Previous: ADE-208-077G)

> Rev.8.00 Nov.06.2003

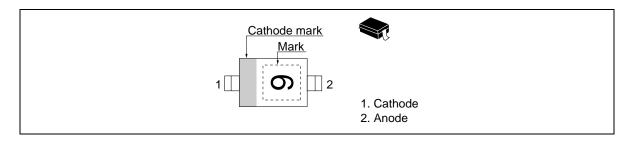
**Features** 

- Low capacitance. (C = 0.8 pF max)
- Low forward voltage.
- Ultra small Resin Package (URP) is suitable for high density surface mounting and high speed assembly.

#### **Ordering Information**

Type No.	Laser Mark	Package Code	
HSU88	9	URP	

#### **Pin Arrangement**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Reverse voltage	$V_R$	10	V
Average rectified current	I <sub>O</sub>	15	mA
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	°C

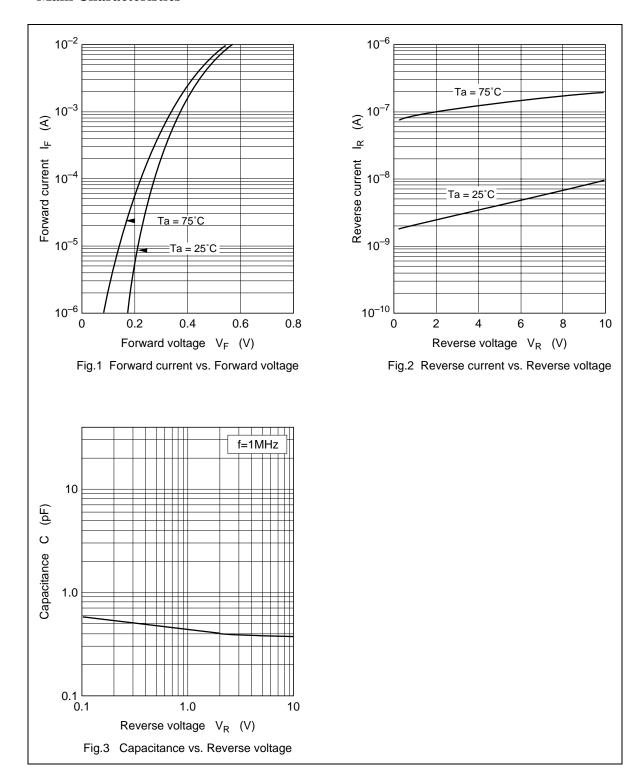
### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

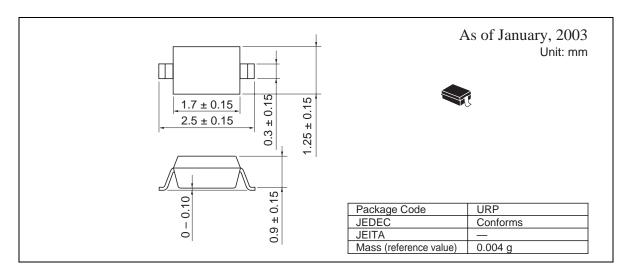
Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	$V_{F1}$	0.35	_	0.42	V	I <sub>F</sub> = 1 mA
	V <sub>F2</sub>	0.50	_	0.58	=	I <sub>F</sub> = 10 mA
Reverse current	I <sub>R1</sub>	_	_	0.2	μΑ	V <sub>R</sub> = 2 V
	I <sub>R2</sub>	_	_	10	=	V <sub>R</sub> = 10 V
Capacitance	С	_	_	0.8	pF	$V_R = 0 V, f = 1 MHz$
ESD-Capability *1	_	30	_	_	V	$C$ = 200 pF, R = 0 $\Omega$ , Both forward and reverse direction 1 pulse.

Notes: 1. Failure criterion ;  $I_R \ge 0.4 \mu A$  at  $V_R = 2 V$ 

#### **Main Characteristics**



## **Package Dimensions**



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